





future ASICs for

calorimetry at OMEGA

Ch. de LA TAILLE CEPC meeting Marseille A

CE

- On-detector embedded electronics, low-power multi-channel ASICs
 - CALICE SKI/SPI/HARDROC, FLAME, CMS HGCROC, FCC LAr, FATIC...
 - Challenges : #channels, low power, digital noise, data reduction
- Off-detector electronics : fiber/crystal readout
 - Wavefrom samplers : DRS, Nalu AARD, LHCb spider...
 - Challenges : low power, data reduction
- Digital calorimetry : MAPs, RPCs...
 - DECAL, ALICE FOCAL, CALICE SDHCAL
 - MAPS for em CAL : eg ALPIDE ASIC for FOCAL, DECAL...
 - Challenges : #channels, low power, data reduction

Digital calorimetry

- Hadronic : e.g. CALICE RPCs or µmegas
 - ~1 cm² pixels, low occupancy, ~1 mW/cm² (unpulsed)
 - Performance improvement with semi-digital architecture
 - Timing capability can be added
- Electromagnetic : e.g. DECAL, ALICE FOCAL...
 - Based on ALPIDE : (30µm)² pixels, high occupancy, ~ few 100 mW/cm², slow
 - To be compared with embedded electronics ~10 mW/cm²
 - Most power in digital processing => would benefit a lot from ≤ 28 nm node
 - Semi-digital and/or larger pixels could be an interesting study
- Upcoming R&D
 - Power reduction, dead area minimizatio
 - Coping with high occupancy, managing data bandwidth





Waveform sampling

- Switched capacitor arrays (DRS4, Nalu, SPIDER...)
 - Pulse shape analysis
 - High accurcay timing, digital CFD
 - Sizeable power to provide GHz BW on large capacitance
 - large data volume
- Often used in off-detector electronics
 - Space and cooling available
 - Small/medium size detector readout and/or characterization
 - See LHCb calorimeter upgrade
- Upcoming R&D
 - Power reduction, Front-end integration
 - Data bandwitdth
 - Time walk correction, potentially best for ps accuracy



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Embedded ASICs



- Pioneered with CALICE R&D (SKIROC, SPIROC..)
- Multi-channel charge/time readout
 - Fast preamp
 - Full dynamic range. Possible extension with ToT
 - Fast path for time measurement (ToA)
 - High speed discriminator and TDC
 - Time walk correction with ADC (or ToT)
 - Slow path for charge measurement
 - ~10 bit ADC ~40 MHz
 - Low power for on-detector implementation (~10 mW/ch) e.g. CMS HGCAL
- Upcoming R&D
 - Power reduction,
 - Auto-trigger, Data-driven readout







Example : HGCROC (CMS HGCAL)



Overall chip divided in two symmetrical parts

- Each half is made of:
 - 39 channels: 36 channels, 2 common-mode, 1 calibration
 - Bandgap, voltage reference close to the edge
 - Bias, ADC reference, Master TDC in the middle
 - Main digital block and 3 differential outputs (2x Trigger, 1x Data)

Measurements

- Charge
 - ADC (AGH): peak measurement, 10 bits @ 40 MHz, dynamic range defined by preamplifier gain
 - TDC (IRFU): TOT (Time over Threshold), 12 bits (LSB = 50ps)
 - ADC: 0.16 fC binning. TOT: 2.5 fC binning
- Time
 - TDC (IRFU): TOA (Time of Arrival), 10 bits (LSB = 25ps)

Two data flows

- DAQ path
 - 512 depth DRAM (CERN), circular buffer
 - Store the ADC, TOT and TOA data
 - 2 DAQ 1.28 Gbps links (CLPS)
- Trigger path
 - Sum of 4 (9) channels, linearization, compression over 7 bits
 - 4 Trigger 1.28 Gbps links (CLPS)

Control

Fast commands.

$Q_{MIP}/Cd \sim 3 \text{ fC}/30 \text{ pF} = 100 \text{ }\mu\text{V}$

I2C protocol for slow control

Ancillary blocks

- Bandgap (CERN)
- 10-bits DAC for reference setting
- 11-bits Calibration DAC for characterization and calibration
- PLL (IRFU)
- Adjustable phase for mixed domain



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Performance













channels

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Zoom on timing



- ~2.5 ns time walk, 13 ps jitter for Q>100fC at Cd = 47 pF
- Fits also well MCPs for PID @EIC (HRPPD)





H2GCROC: SiPM version current conveyor

- Current conveyor (Heidelberg design) to adapt to Si version
- Dynamic range : 50 fC 300 pC
- 2 typical gains
 - Low gain (Physics mode): 44 fC/ADC gain, 50 fC noise (1.25 ADCu)
 - High gain (Calibration mode): 10 fC/ADC gain, 20 fC noise (2 ADCu)
- $\circ~$ Measurements in backup slides







HGCROC : ADC and TOT

- ADC range 0 200 fC
- TOT range 200 fC 10 pC
- Non-linear inter-region
- 200 ns dead time
- Not well adapted to SiPM version
- => go to dynamic gain switching





Chips for EIC : electron-ion collider at BNL

- PID and calorimeters
 - EICROC for AC-LGAD roman pots
 - H(2)GCROC for calorimeters

mRICH

TOF

« Event driven » DAQ



Detector	Channels				
Group	MAPS	AC/DC-LGAD	SiPM/PMT	MPGD	
Tracking	32 B			100k	
Calorimeters	50M		67k		
Far Forward	300M	2.3M	500		
Far Backward		1.8M	700		
PID		3M-50M	600k		
TOTAL	32 B	7.1M-54M	670k	100k	
ASIC	ITS-3	EICROC FCFD HPsOC ASROC FAST	Discrete/COTS HGCROC3 AL COR-E IC	SALSA	





HKROC main features



HKROC is 36 channels: 12 PMTs with High, Medium and Low gain



- □ Large charge measurement with 3 gains (up to 2500 pC)
- □ Integrated timing measurements (25 ps binning)
- □ Readout with high speed links (1,28 Gb/s)
- □ HKROC is a waveform digitizer with auto-trigger

HKROC: waveform digitizer with auto-trigger

- □ HKROC is waveform digitizer working @ 40 MHz
 - Number of charge sampling points from 1 to 7
 - □ Fast channel for precise timing (25 ps binning)
 - □ Charge reconstruction algorithm in FPGA
 - 5% resources of a modern XILINX FPGA



When using 3 gains / PMT (high, medium, low)

- □ Hit rate capability up to 400 kHz / PMT
- □ Increased up to 1 MHz by focusing on high gain
 - Dynamic selectable by the user
- Average values only limited by readout speed

Measurements in backup slides

Normal mode	Supernovae mode	High speed mode
Rate 400 k/chn	~1M /chn	40 M

HKROC can accept consecutive events (separated by ~30 ns)

Internal HKROC memory writing is without dead time Readout speed is only limited by serial link bandwidth (average values above)

DRD6 Common readout ASICs proposal [AGH, Omega, Saclay]

- Develop readout ASIC family for DRD6 prototype characterization
 - Inspired from CALICE SKIROC/SPIROC/HARDROC/MICROROC family
 - Targeting future experiments as mentionned in ICFA document (EIC, FCC, ILC, CEPC...)
 - Addressing embedded electronics and detector/electronics coexistence + joint optimization
 - Detector specific front-end but common backend
 - \Rightarrow allows common DAQ and facilitates combined testbeam
- Start from HGCROC / HKROC : Si and SiPM
 - Reduce power from 15 mW/ch to few mW/ch. Lower occupancy, slower speed
 - Allows better granularity or LAr operation
 - Remove HL-LHC-specific digital part and provide flexible auto-triggered data payload
 - Extend to MCPs (PID) or HRPPD. First tests with EIC calo/PID
- Several other ASICs R/Os also developed in DRD6 and it is good !
 FLAME/FLAXE, FATIC...
 - Waveform samplers : commercial or specific (e.g. SPIDER)
 - DECAL









CALOROC1 (2024)

- SiPM readout calorimetry : CMS H2GCROC with EIC readout (200 MHz clock and fast commands)
 - SiPM from 500 pF to 2.5 nF (or 10 nF)
 - ~5-10 mW/channel
- 2 versions : conservative and exploratory
 - Conservative : uses H2GCROC (ADC, TOT) as it is and replaces the backend
 - Exploratory : new analog part (dynamic gain switching).
 - Pin to pin compatible
 - Backend « à la HKROC » : auto-triggered, zero-suppressed
 - 40 MHz internal clocking (ADC, TDCs)
- Channel number tbd : 32 (HKROC) or 64 (HGCROC)
- Could fit FCC SiPM calorimeters
- A Si version would fit FCC Si calorimeter



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HKROC

CALOROC1A (also 2024)

Omega

- Variant with new analog part
- Dynamic gain switching
- Study of current conveyor and voltage amplifiers « à la spiroc »
- Study low power ADCs (clock gating)
- Will fit (most) DRD6 needs





Technology choice for mixed signal ASICs

- TSMC 130nm : mixed signal, cheap
 - Very mature technology with good analog performance
 - 2.5 k€/mm² MPW, 300-350 k€/engineering run (20 wafers C4)
 - Perenity ?
- TSMC 65 nm : mixed signal, main stream
 - ~2-3 times lower power in digital, similar in the analog (compared to 130n)
 - 5 k€/mm², 700-800 k€/ engineering run
- TSMC 28 nm : digital oriented
 - High density integration (pixels)
 - High performance, lower power digital, similar in the analog
 - 10 k€/mm², 1-1.5 M€/ eng run







conclusion



- Importance of joint optimization detector/readout electronics
- Trend to reduce power and data volume
 - Pileup will be less of an issue, better granularity will be appreciated !
 - Low occupancy, auto-trigger, data-driven readout
 - Low power ADCs and TDCs (DRD7 with AGH&CEA)
- Picosecond Timing important R&D area
 - PID and/or calorimetry, several new detectors appearing : need R/O
- Next chips at OMEGA will target EIC, DRD1-4-6-7
 - Calorimetry and timing : CALOROC1 and 1A
 - Mid 2024
 - Further R&D needed to bring power down to ~1 mW/ch (Lar)
- Technology choice to be addressed in coordination with other design groups
 - Cost sharing for engineering runs





DRD6 (calorimetry) readout schemes



Name	Track	Active media	readout
LAr	2	LAr	cold/warm elx"HGCROC/CALICElike ASICs"
ScintCal	3	several	SiPM
Cryogenic DBD	3	several	TES/KID/NTL
HGCC	3	Crystal	SiPM
MaxInfo	3	Crystals	SIPM
Crilin	3	PbF2	UV-SiPM
DSC	3	PBbGlass+PbW04	SiPM
ADRIANO3	3	Heavy Glass, Plastic Scint, RPC	SIPM
FiberDR	3	Scint+Cher Fibres	PMT/SiPM,timing via CAENFERS, AARDVARC-v3,DRS
SpaCal	3	scint fibres	PMT/SiPMSPIDER ASIC for timing
Radical	3	Lyso:CE, WLS	SiPM
Grainita	3	BGO, ZnWO4	SiPM
TileHCal	3	organic scnt. tiles	SiPM
GlassScintTile	1	SciGlass	SiPM
Scint-Strip	1	Scint.Strips	SiPM
T-SDHCAL	1	GRPC	pad boards
MPGD-Calo	1	muRWELL,MMegas	pad boards(FATIC ASIC/MOSAIC)
Si-W ECAL	1	Silicon sensors	direct withdedicated ASICS (SKIROCN)
Si/GaAS-W ECAL	1	Silicon/GaAS	direct withdedicated ASICS (FLAME, FLAXE)
DECAL	1	CMOS/MAPS	Sensor=ASIC
AHCAL	1	Scint. Tiles	SiPM
MODE	4	-	-
Common RO ASIC	4	-	common R/O ASIC Si/SiPM/Lar

ADC and TOT readout

- 16bit dynamic range split in 10 bit ADC and 12 bit ToT
- Tests with 2 sizes of SiPM : 2mm² (120 pF) and 9 mm² (560 pF)









Physics mode : test pulse injection

 \circ ~ 60 fC minimum detectable charge efficiently, up to 320pC





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High range injection (TOT):





- The CC gain has good performance in linearity.
- The increment in noise is due to the gain configuration and the detector capacitance of the SiPM.



CC gain scan:









- The increase in noise due to larger C_{det} shifts the minimum charge associated with TOA data.
- The thresholds can be adjusted channel-wise for a uniform performance.

Effect of C_{det} on TOA:

- Larger C_{det} produce larger time walk due to the duration of the signal.
- Increasing C_{det} delayed the achievement of a 100ps resolution in charge injection.





Calibration mode: Single-photon-spectrum



Also a different configuration of the ASIC is necessary to increase the SNR.

2mm²:

- CC gain attenuation = **0.3**
- $R_f = 16.6 k\Omega$
- $C_{f_total} = 600 fF (C_f + C_{fcomp})$

9mm²:

- CC gain attenuation = 0.375
- $R_f = 16.6 k\Omega$
- $C_{f_{total}} = 300 fF$ (To make the pulse shorter)





*Noise measured with the same configuration parameters for all C_{det} .

- The increment in noise is due to the detector capacitance of the SiPM.
- SNR can be improved with the gain configuration.

CMS

Calibration mode: Single-photon-spectrum





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*Extra step for 9mm² SiPM calibration:

The large C_{det} of the 9mm² SiPM produce an increment of DNL and make it harder to see the photon separation.

The DNL can be mitigated taking data with different pedestal levels using the ASIC to move the pedestals (*Trim_inv* parameter). SPS is clearer after aligning the data.

